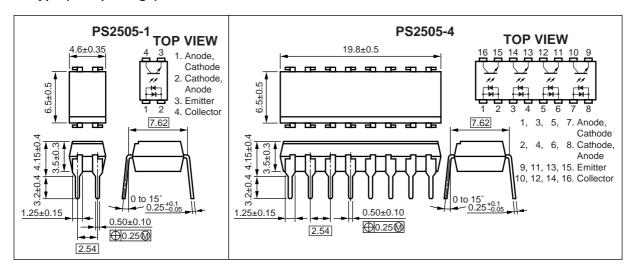
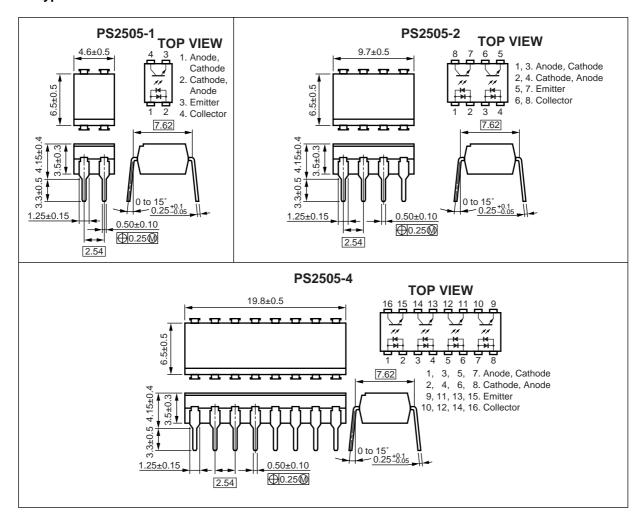
★ PACKAGE DIMENSIONS (UNIT : mm)

DIP Type (New package)

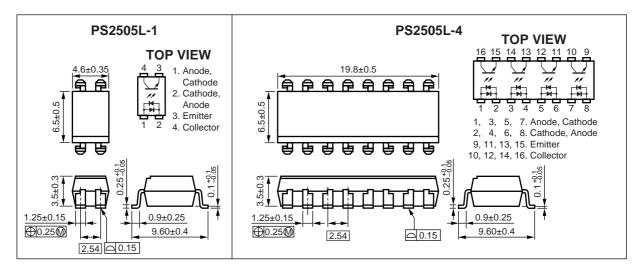


Caution New package 1-ch, 4-ch only

DIP Type

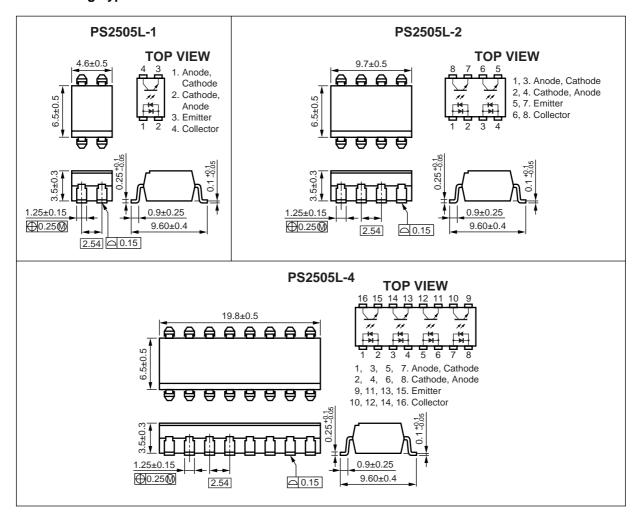


Lead Bending Type (New package)

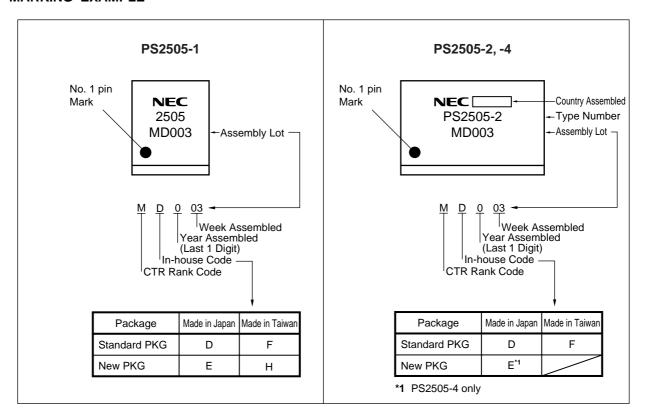


Caution New package 1-ch, 4-ch only

Lead Bending Type



★ MARKING EXAMPLE



ORDERING INFORMATION (Solder Contains Lead)

Part Number	Package	Packing Style	Application Part Number*1
PS2505-1	4-pin DIP	Magazine case 100 pcs	PS2505-1
PS2505L-1			
PS2505L-1-E3		Embossed Tape 1 000 pcs/reel	
PS2505L-1-E4			
PS2505L-1-F3		Embossed Tape 2 000 pcs/reel	
PS2505L-1-F4			
PS2505-2	8-pin DIP	Magazine case 45 pcs	PS2505-2
PS2505L-2			
PS2505L-2-E3		Embossed Tape 1 000 pcs/reel	
PS2505L-2-E4			
PS2505-4	16-pin DIP	Magazine case 20 pcs	PS2505-4
PS2505L-4			

^{*1} For the application of the Safety Standard, following part number should be used.

ORDERING INFORMATION (Pb-Free)

Part Number	Package	Packing Style	Application Part Number*1
PS2505-1-A	4-pin DIP	Magazine case 100 pcs	PS2505-1
PS2505L-1-A			
PS2505L-1-E3-A		Embossed Tape 1 000 pcs/reel	
PS2505L-1-E4-A			
PS2505L-1-F3-A		Embossed Tape 2 000 pcs/reel	
PS2505L-1-F4-A			
PS2505-2-A	8-pin DIP	Magazine case 45 pcs	PS2505-2
PS2505L-2-A			
PS2505L-2-E3-A		Embossed Tape 1 000 pcs/reel	
PS2505L-2-E4-A			
PS2505-4-A	16-pin DIP	Magazine case 20 pcs	PS2505-4
PS2505L-4-A			

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter			Rat		
		Symbol	PS2505-1, PS2505L-1	PS2505-2,-4 PS2505L-2,-4	Unit
Diode	Forward Current (DC)	lF	±8	30	mA
	Power Dissipation Derating	⊿P₀/°C	1.5	1.2	mW/°C
	Power Dissipation	Po	150	120	mW/ch
	Peak Forward Current*1	I FP	±1		Α
Transistor	Collector to Emitter Voltage	VCEO	80		V
	Emitter to Collector Voltage	VECO	7		V
	Collector Current	lc	50		mA/ch
	Power Dissipation Derating	⊿Pc/°C	1.5	1.2	mW/°C
	Power Dissipation	Pc	150	120	mW/ch
Isolation Voltage*2		BV	5 000		Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100		°C
Storage Temperature		T _{stg}	-55 to +150		°C

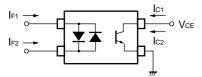
^{*1} PW = 100 μ s, Duty Cycle = 1 %

^{*2} AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

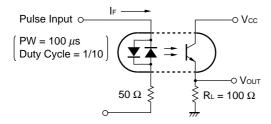
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	$I_F = \pm 10 \text{ mA}$		1.17	1.4	V
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		100		pF
Transistor	Collector to Emitter Dark Current	ICEO	VcE = 80 V, IF = 0 mA			100	nA
Coupled	Current Transfer Ratio	CTR	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	80	300	600	%
	CTR Ratio*1	CTR1/ CTR2	IF = 5 mA, VcE = 5 V	0.3	1.0	3.0	
	Collector Saturation Voltage	VCE(sat)	I _F = ±10 mA, I _C = 2 mA			0.3	V
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.5		pF
	Rise Time*2	tr	$Vcc = 10 \text{ V}, \text{ Ic} = 2 \text{ mA}, \text{ R}_L = 100 \Omega$		3		μS
	Fall Time*2	tr			5		

*1 CTR1 = Ic1/IF1, CTR2 = Ic2/IF2

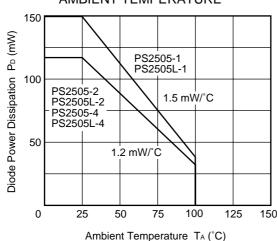


*2 Test circuit for switching time

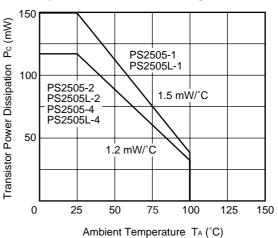


TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

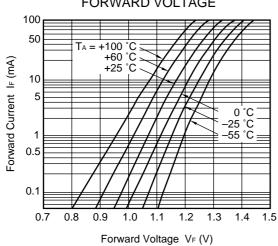




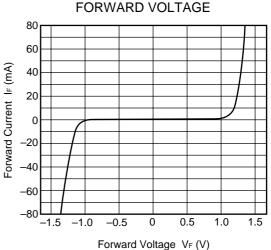
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



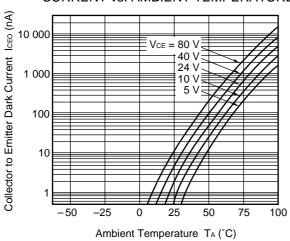
FORWARD CURRENT vs. FORWARD VOLTAGE



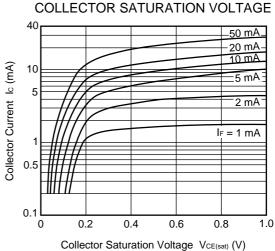
FORWARD CURRENT vs.



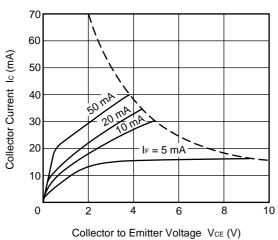
COLLECTOR TO EMITTER DARK **CURRENT vs. AMBIENT TEMPERATURE**



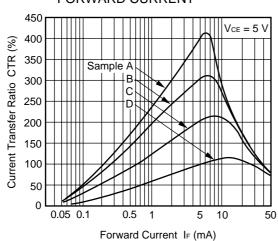
COLLECTOR CURRENT vs.



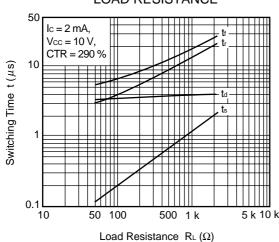
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



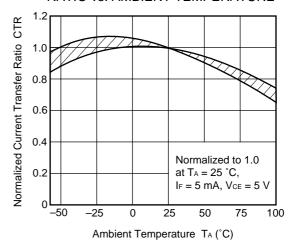
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



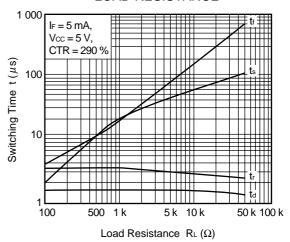
SWITCHING TIME vs. LOAD RESISTANCE



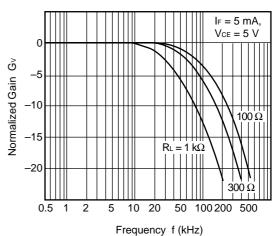
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE

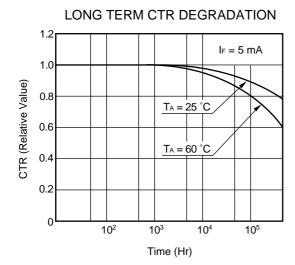


SWITCHING TIME vs. LOAD RESISTANCE



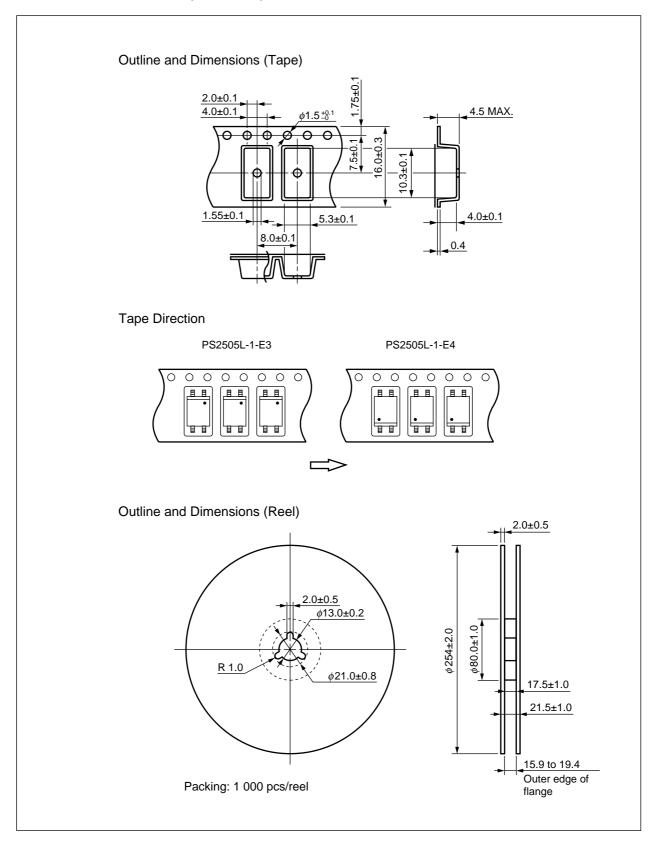
FREQUENCY RESPONSE

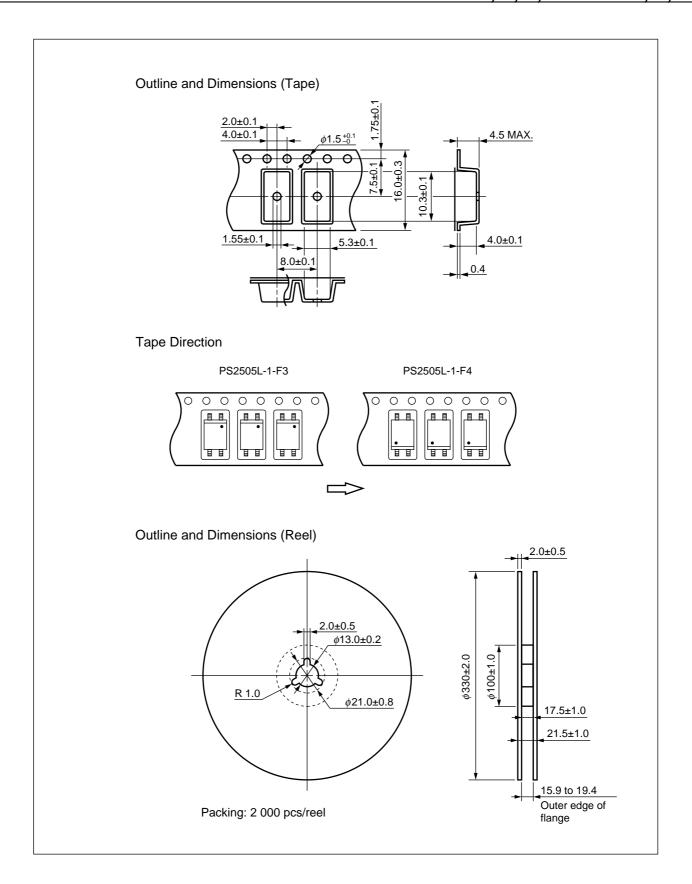


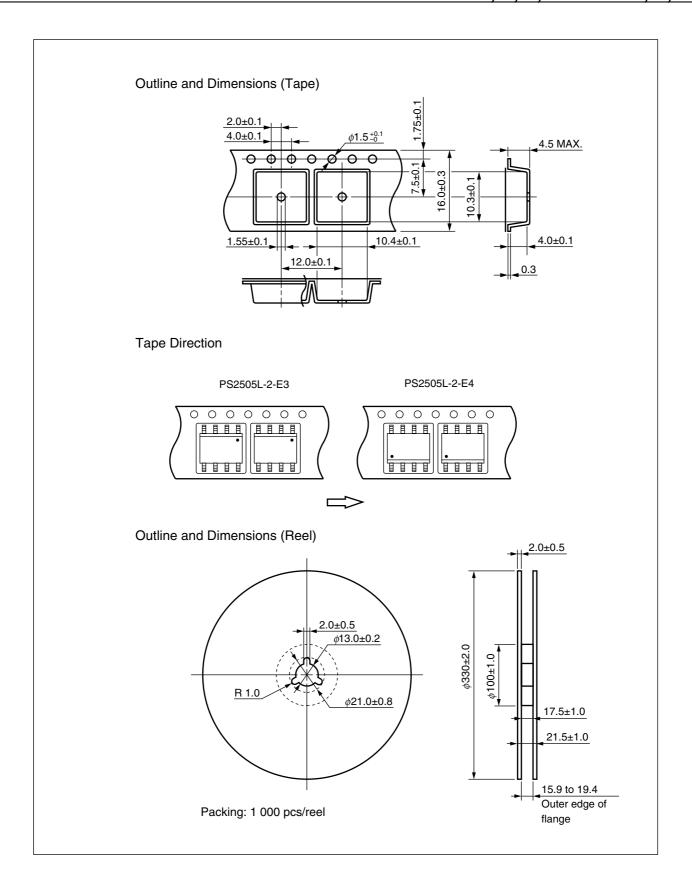


Remark The graphs indicate nominal characteristics.

★ TAPING SPECIFICATIONS (UNIT : mm)







NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature 260°C or below (package surface temperature)

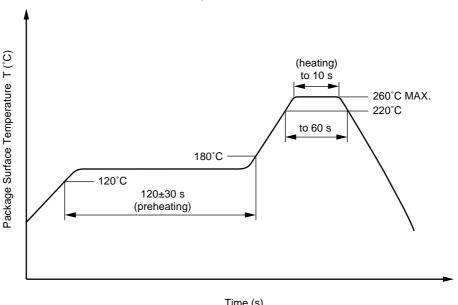
• Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s · Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

★ USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerting the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

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